

Description

The DPO2036 provides 4 channels of over-voltage protection over the CC1/2 & SBU1/2 pins which are connected to the USB Type-C[®] connector. The 4 channels are divided into two pairs, one pair of channels protect the CC1 and CC2 pins from being shorted to the V_{BUS}, one pair of channels protect the SBU1 and SBU2 pins from being shorted to the V_{BUS}. Whenever the voltage threshold set for any of the two pairs of channels is reached, the exception condition becomes valid and the low-active flag FAULTB is subsequently asserted.

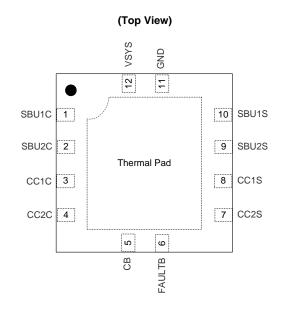
This device is designed to draw its operating voltage primarily from the system power, V_{VSYS}, which is either the always-ON 3.3V/5Vexisted within the system or the 1-cell battery inside the mobile system. Under the circumstance when the battery inside a mobile system is fully depleted, DPO2036 can obtain power from the external peripheral system connected to the USB Type-C connector. The DPO2036 supports the dead battery mode by having both of the CC1C and CC2C pins tied to the pull-down resistor R_D (resistor value per the USB Type-C Specification) embedded in the device.

The DPO2036 is housed in the low-profile and space-saving U-QFN2020-12 (Type B) package which is manufactured with environmental-friendly material.

Features

- Operating Voltage Range: 2.7V to 5.5V
- 4-Channel Over-Voltage Protection with Auto-Recovery
- R_{DS(ON)} of OVP MOSFET for CC-Pin Protection: 350mΩ Typical
- R_{DS(ON)} of OVP MOSFET for SBU-Pin Protection: 5Ω Typical
- C_{IN} of OVP MOSFET for CC-Pin Protection: 50pF
- CIN of OVP MOSFET for SBU-Pin Protection: 5pF
- Dead Battery Support for CC Lines
- Built-In Over-Temperature Protection
- IEC61000-4-2 ESD Protection on CC1C, CC2C, SBU1C, SBU2C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Pin Assignments



U-QFN2020-12 (Type B)

Applications

- Notebook/Desktop/AIO PCs, Tablets, Mobile Phones
- VR/AR Headsets
- Docking Stations, Universal & Multimedia Hubs
- FPTVs, PC Monitors
- Set-Top-Boxes, Residential Gateways, Storage Devices
- Universal AC/DC Chargers/Adapters

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

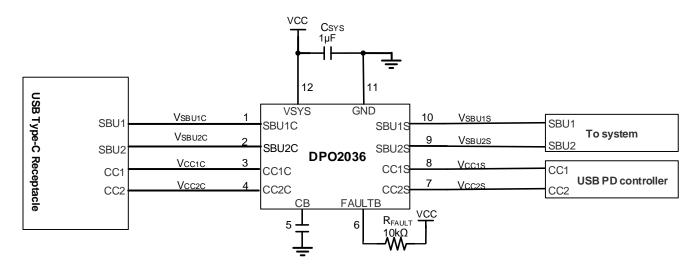
. See https://www.diode Lead-free

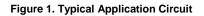
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



DPO2036

Typical Application Circuit





Pin Descriptions

Pin Number	Pin Name	Function
1	SBU1C	SBU1 connector side. This shall be connected to the SBU1 pin of the USB Type-C connector.
2	SBU2C	SBU2 connector side. This shall be connected to the SBU2 pin of the USB Type-C connector.
3	CC1C	CC1 connector side. This shall be connected to the CC1 pin of the USB Type-C connector.
4	CC2C	CC2 connector side. This shall be connected to the CC2 pin of the USB Type-C connector.
5	СВ	Pin for ESD support capacitor. Place a 0.1µF capacitor on this pin to ground
6	FAULTB	Fault status. This is an active-low open-drain output.
7	CC2S	CC2 system side. This shall be connected to the CC2 pin of the component to be protected.
8	CC1S	CC1 system side. This shall be connected to the CC1 pin of the component to be protected.
9	SBU2S	SBU2 system side. This shall be connected to the SBU2 pin of the component to be protected.
10	SBU1S	SBU1 system side. This shall be connected to the SBU1 pin of the component to be protected.
11	GND	Ground.
12	VSYS	Power Input. This shall be connected to the 2.7 to 5.5V power source inside the system.
	Thermal Pad	Need to connect pad to the PCB ground plane. It serves as a heatsink.



DPO2036

Functional Block Diagram

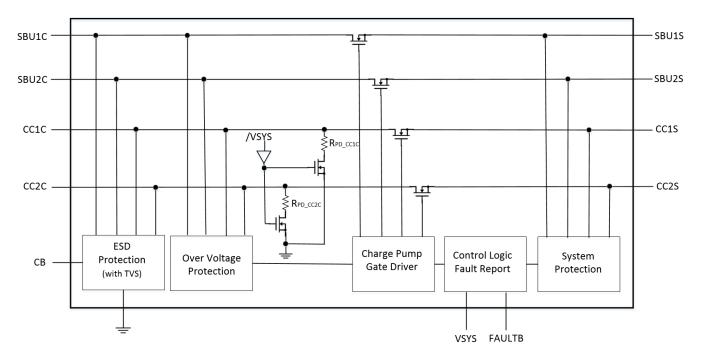


Figure 2. Internal Functional Blocks



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.) (Note 4)

Symbol	Parameter	Rating	Unit
V _{VSYS} Voltage Range of VSYS Pin		-0.3 to 6.0	V
VFAULTB	Voltage Range of FAULTB Pin	-0.3 to 6.0	V
VSBUXS, VCCXS	Voltage Range of SBU1S, SBU2S, CC1S, CC2S Pins	-0.3 to 6.0	V
V _{SBUxC} , V _{CCxC} Voltage Range of SBU1C, SBU2C, CC1C, CC2C Pins		-0.3 to 24.0	V
TJ	Operating Junction Temperature	-40 to +125	°C
T∟	Lead Temperature	+260	°C
T _{STG} Storage Temperature		-65 to +150	°C
ESD	Human Body Model (HBM), JESD22-A114	±2.0	kV
E9D	Charge Device Model (CDM), JESD22-C101	±0.5	κv

Note: 4. These are stress ratings only. Operation outside the absolute maximum ratings can cause device failure. Operation at the absolute maximum rating for extended periods can reduce device reliability.

Package Thermal Data (@ T_A = +25°C, unless otherwise specified.) (Note 5)

Symbol	Parameter	Rating	Unit
PD	Power Dissipation	1.3	W
Reja	Thermal Resistance, Junction-to-Ambient	96	°C/W
Rejc	Thermal Resistance, Junction-to-Case	26	°C/W

Note: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1" × 1" copper pad layout.

Recommended Operating Conditions (@ T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Мах	Unit
Vvsys	Input Supply Voltage at VSYS Pin	2.7	5.5	V
VFAULTB	Power Rail for Pull-up on FAULTB Pin	2.7	5.5	V
Vccxc, Vccxs	I/O Voltage at CC1C, CC2C, CC1S, CC2S Pins	-0.25	5.5	V
VSBUXC, VSBUXS	I/O Voltage at SBU1C, SBU2C, SBU1S, SBU2S Pins	-0.25	4.2	V
Ivconn	Output Current Flowing Into CCxS and out of CCxC, with V _{CCxS} – V _{CCxC} \leq 250mV	_	600	mA



Electrical Characteristics (@ T_A = +25°C, V_{VSYS} = 4.2V, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
CC OVP Switches	•	•		•	•	•
_		V _{CCxC} = 5.5V, T _A ≤ +85°C	_	350	500	mΩ
Rds(on)_cc	On Resistance of CC OVP FETs	$V_{CCxC} = 5.5V, T_A \le +105^{\circ}C$	—	350	520	mΩ
RDS(ONFLAT)_CC	On Resistance Flatness of CC OVP FETs	V _{CCxC} = 0.1V to 1.2V	—	—	5	mΩ
Con_cc	Equivalent ON Capacitance	Capacitance from CCxC or CCxS to GND when device is powered, (V _{CCxC} $/$ V _{CCxS}) = 0V to 1.2V	_	50	_	pF
Rpd_ccxc	Dead Battery Pull-Down Resistance on CCxC Pin	$V_{CCxC} = 2.6V$	4.10	5.1	6.10	kΩ
VTH_RPD_CCxC	Threshold Voltage of the Pulldown FET for in Series with RPD_CCxC	$I_{CCxC} = 100 \mu A$	1.2	1.4	1.6	V
VTH_OVP_CCxC	OVP Threshold on CCxC Signal	—	5.6	6	6.25	V
VTH_OVP_HYS_CCxC	OVP Hysteresis on CCxC Signal	—	_	140	_	mV
BWon_cc (Note 6)	CC Line ON Bandwidth Single Ended (-3dB)	Measured from CCxC to CCxS, 50Ω system, V _{CM} = 0.1V to 1.2V	_	200	_	MHz
Vsht_ccxc_max (Note 6)	Short-to-VBUS Tolerance on the CCxC Pins	Hot-plug CCxC with a 1 meter USB Type-C cable, place a 30Ω load on CCxS	_	_	22	V
VsHT_CCxs_CL (Note 6)	Short-to-VBUS Clamping Voltage on the CCxS Pins	Hot-plug CCxC with a 1 meter USB Type-C cable, place a 30Ω load on CCxS. Hot plug voltage V _{CCxC} = 24V	_	7	_	V
SBU OVP Switches	•	· · · · ·			•	•
5		V _{SBUxC} = 3.6V, T _A = +85°C		5	_	Ω
Rds(on)_sbu	On Resistance of SBU OVP FETs	V _{SBUxC} = 3.6V, T _A = +105°C	_	5	—	Ω
Rds(onflat)_sbu	On Resistance Flatness of SBU OVP FETs	V _{SBUxC} = 0.1V to 3.6V	_	_	1	Ω
Con_sbu	Equivalent ON Capacitance	Capacitance from SBUxC or SBUxS to GND when device is powered. V _{SBUxC} / V _{SBUxS} = 0V to 3.6V	_	5	_	pF
VTH_OVP_SBUxC	OVP Threshold on SBUxC Signals	—	4.15	4.5	4.75	V
VTH_OVP_HYS_SBUxC	OVP Hysteresis on SBUxC Signals	—	—	110	—	mV
BWon_seu (Note 6)	SBU Line ON Bandwidth Single Ended (-3dB)	Measured from SBUxC to SBUxS, 50Ω system, V _{CM} = 0.1V to 3.6V	_	600	_	MHz
Vshtbus_sbuxc_max (Note 6)	Short-to-VBUS Tolerance on the SBUxC Pins	Hot-plug SBUxC with a 1 meter USB Type-C cable, place a 40Ω in series with 150nF to GND on SBUxS pin	_	_	22	V
Vshtbus_sbuxs_cl (Note 6)	Short-to-VBUS Clamping Voltage on the SBUxS Pins	Hot-plug SBUxC with a 1 meter USB Type-C cable, place a 40Ω in series with 100nF to GND on SBUxS pin. Hot plug voltage V _{SBUxC} = 24V, V _{VSYS} = 3.3V	_	7	_	v
XTALK_SBUx (Note 6)	Crosstalk between SBUx Lines	Measure crosstalk at f = 1MHz, from SBU1S to SBU2C or SBU2S to SBU1C. $V_{CM1} = 3.6V$, $V_{CM2} = 0.3V$, terminate open sides to 50Ω	_	-80	_	dB

Note: 6. Guaranteed by bench characterization.



Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Power Supply and Le	eakage Current				•	•
Vuvlo	Vvsys Under Voltage Lockout	Vvsys steps up from 2V until CC or SBU FETs turn ON	2.15	2.4	2.55	V
Vuvlo_hsys	Vvsys UVLO Hysteresis	V _{VSYS} steps down from 2.5V until CC or SBU FETs turn off. Measure difference between rising and falling UVLO to calculate	_	200	_	mV
IVSYS_ON	Vvsvs Supply Current	—	—	190	—	μA
ILEAK_CCxC	Leakage current for CCxC when device is Powered	VCCxC = 3.6V	_	_	30	μA
ILEAK_SBUXC	Leakage current for SBUxC when device is Powered	V _{SBUxC} = 3.6V	_	_	35	μA
ILEAK_CCxS	Leakage Current for CCxS when device is Powered	Vccxs = 3.6V	—	—	30	μA
ILEAK_SBUXS	Leakage current for SBUxS when device is Powered	V _{SBUxS} = 3.6V	_	—	35	μA
ILEAK_OVP_CCxC	Leakage current into CCxC pins when	Vvsys = 0V, Vccxc = 21V, Vccxs = 0V	—	_	6	mA
	device is in OVP	$V_{VSYS} = 4.2V, V_{CCxC} = 21V, V_{CCxS} = 0V$			150	μA
ILEAK OVP SBUXC	Leakage current into SBUxC pins when	Vvsys = 0V, Vsbuxc = 21V, Vsbuxs = 0V			200	μA
	device is in OVP	$V_{VSYS} = 4.2V, V_{SBUxC} = 21V, V_{SBUxS} = 0V$	—	_	200	μA
ILEAK_OVP_CCxS	Leakage current out of CCxS pins when	Vvsys = 0V, Vccxc = 21V, Vccxs = 0V	_	—	1	μA
ILEAR_OVP_CCX3	device is in OVP	$V_{VSYS} = 4.2V, V_{CCxC} = 21V, V_{CCxS} = 0V$		_	1	μA
	Leakage current out of SBUxS pins when	Vvsys = 0V, Vsbuxc = 21V, Vsbuxs = 0V		_	1	μA
ILEAK_OVP_SBUXS device is in OVP		Vvsys = 4.2V, Vsbuxc = 21V, Vsbuxs = 0V	_	—	1	μA
FAULTB Pin					-	-
VFAULTB	Active-Low Output Voltage of FAULTB Pin	I _{OL} = 8mA	—	—	0.4	V
LEAK_FAULB	FAULTB Leakage Current	V _{FAULTB} = 4.2V	—	—	1	μA
t FAULTB_ASSERTION	FAULTB Assertion Time	—	—	—	300	μs
tFAULTB_DEASSERTION	FAULTB Deassertion Time	—	_	4	—	ms
Timing Requirements	5	·		•		
ton	Time from crossing rising V _{VSYS} UVLO until CC/SBU OVP FETs are on	_	_	_	2.5	ms
tovp_response_cc	OVP response time on the CC pins, time from OVP asserted until OVP FETs turnoff	—	_	100	_	ns
tovp_response_sbu	OVP response time on the SBU pins, time from OVP asserted until OVP FETs turnoff	_	_	100		ns
tovp_response_cc_1	OVP recovery time on the CC pins. Once an OVP has occurred, the minimum duration until CC FETs turn back on if OVP has been removed already	_	26	32	38	ms
tovp_response_sbu_1	OVP recovery time on the SBU pins. Once an OVP has occurred, the minimum duration until SBU FETs turn back on if OVP has been removed already	_	26	32	38	ms
tovp_response_cc_2	OVP recovery time on the CC pins. Time from OVP removal until CC FETs turn back on, if device has been in OVP > 40ms	_		1		ms
tovp_response_sbu_2	OVP recovery time on the SBU pins. Time from OVP removal until SBU FETs turn back on, if device has been in OVP > 40ms	_	_	1	_	ms
Thermal Shutdown a	nd Hysteresis					_
T _{SHDN}	Thermal Shut Down Theshold	—	—	+150	—	°C
THSYS	Thermal Shut Down Hysteresis	_	_	+20	_	°C

Electrical Characteristics (@ $T_A = +25^{\circ}C$, $V_{VSYS} = 4.2V$, unless otherwise specified.) (continued)



Performance Characteristics (@ T_A = +25°C, unless otherwise specified.)

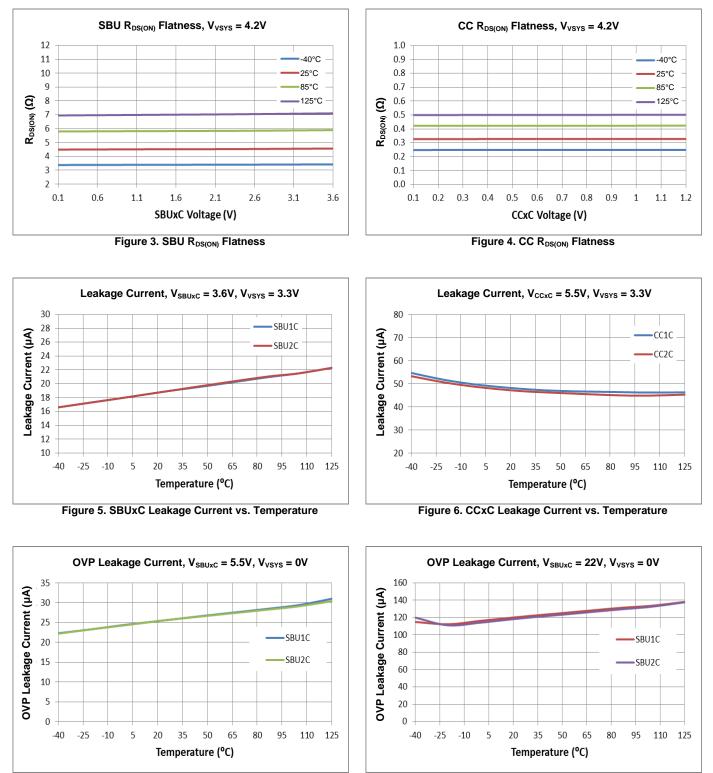


Figure 7. SBUxC 5.5V OVP Leakage Current vs. Temperature



Performance Characteristics (@ TA = +25°C, unless otherwise specified.) (continued)

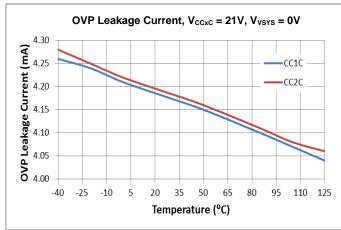


Figure 9. CCxC OVP Leakage Current vs. Temperature

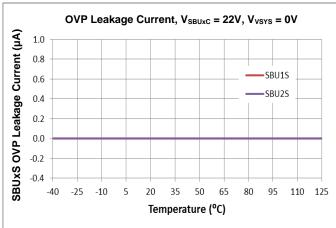


Figure 11. SBUxS OVP Leakage Current vs. Temperature

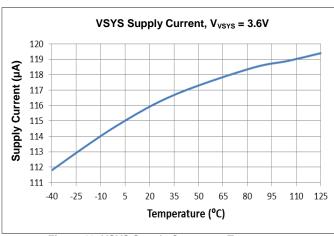


Figure 13. VSYS Supply Current vs Temperature

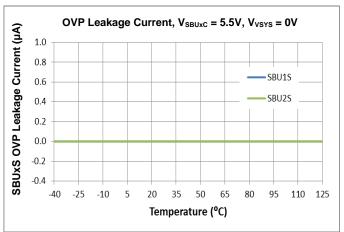


Figure 10. SBUxS OVP Leakage Current vs. Temperature

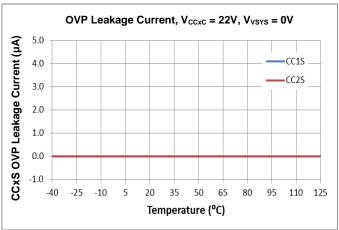
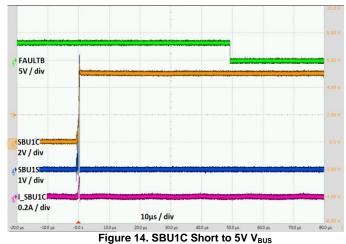
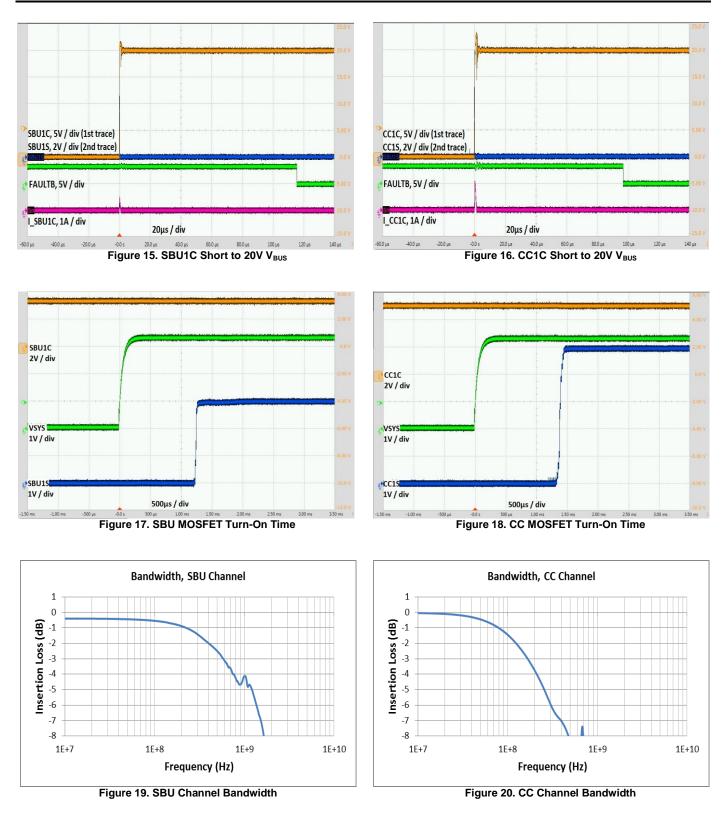


Figure 12. CCxS OVP Leakage Current vs. Temperature





Performance Characteristics (@ T_A = +25°C, unless otherwise specified.) (continued)





Performance Characteristics (@ T_A = +25°C, unless otherwise specified.) (continued)

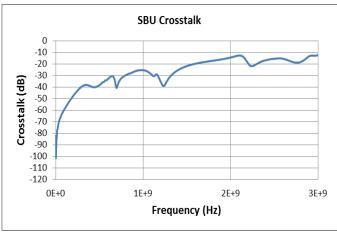


Figure 21. SBU Crosstalk



Application Information

General Description

The DPO2036 is a USB port protection device designed to work with USB Type-C connector, cable and USB PD to form a system that enables signal management and power delivery in a compact package. It provides short to VBUS protection for the CC and SBU pins over the USB Type-C connector, and supports the dead battery mode of operation in an end system / product where the embedded battery is fully depleted.

Short to VBUS Protection

The DPO2036 is a 4-channel uni-directional power switch with over-voltage protection. This is used to prevent the components inside a system which adopts the USB Type-C connector from being damaged by unexpected hazard. On the USB Type-C connector, the CC and SBU pins are located in the close proximity of the VBUS pin. If ever the CC and/or the SBU lines are short to the VBUS line either at the USB-C connector or at the cable end, the components (mostly ICs manufactured on the various sub-micron process nodes) behind the USB Type-C connector can easily be damaged by the resulting EOS. The damage, if occurred, is likely non-recoverable especially given that the voltage level on the VBUS line can go up to 20V or slightly higher. The DPO2036 integrates four series over-voltage FETs to protect the system side CC and SBU lines. When either line on the Type-C connector side CC1C, CC2C, SBU1C or SBU2C is shorted to VBUS line, the DPO2036 will turn off the over-voltage FETs in less than 100ns window to isolate the system side CC and SBU lines from the over-voltage connector side. When shorted to VBUS line is detected, the open-drain FAULTB will output low to indicate a fault condition.

Dead Battery Charging and Power Delivery

In a battery-powered system, the pull-down resistors embedded inside DPO2036 are turned ON and connected to the CC1C/CC2C pins whenever the battery is depleted. Subsequently, the battery-powered system shall receive power through the USB Type-C connector from the external device connected. As soon as the embedded battery is sufficiently recharged to power the system and DPO2036, the pull-down resistors shall be disconnected from the CC1C/CC2C pins.

Signal Operation Range

Table 1 and Table 2 show the signal operation range and output status:

	0V to 5.85V	OFF: Dead Battery RPD Inserted
0V to UVLO (Invalid)	5.85V to 20V	OFF: Dead Battery RPD Inserted
	0V to 5.85V	ON
2.7V to 5.5V (Valid)	5.85V to 20V	OFF: FAULTB Asserted (OVP detected)

Table 1. Signal Operation Range for CCx

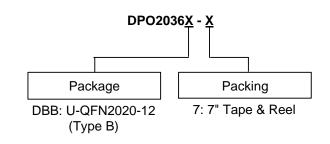
	0V to 4.35V	OFF
0V to UVLO (Invalid)	4.35V to 20V	OFF
	0V to 4.35V	ON
2.7V to 5.5V (Valid)	4.35V to 20V	OFF: FAULTB Asserted (OVP detected)

Table 2. Signal Operation Range for SBUx

DPO2036



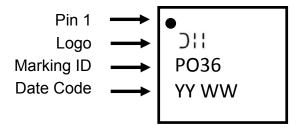
Ordering Information (Note 7)



Part Number	Marking ID	Reel Size (inches)	Tape Width (mm)	7" Tape and Reel		
Fait Number	Marking ID Reel Size	Reel Size (inches)	rape width (mm)	Quantity	Part Number Suffix	
DPO2036DBB-7	PO36	7	8	3,000/Tape & Reel	-7	

Note: 7. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

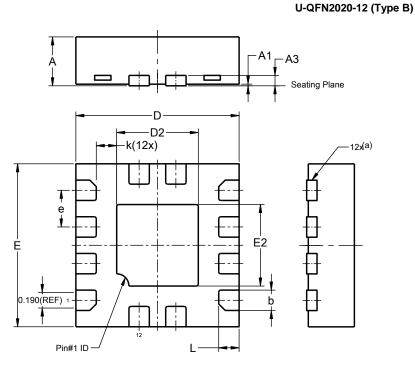


YY: Year WW: Week 01~53



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

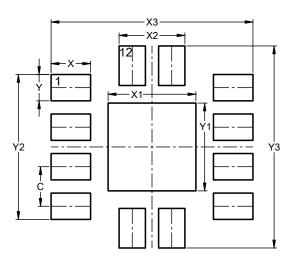


L	U-QFN2020-12 (Type B)					
Dim	Min	Max	Тур			
Α	0.55	0.65	0.60			
A1	0.00	0.05	0.02			
A3			0.13			
b	0.20	0.30	0.25			
D	1.95	2.05	2.00			
D2	0.90	1.10	1.00			
Е	1.95	2.05	2.00			
E2	0.90	1.10	1.00			
е		0.45 B	SC			
k			0.25			
L	0.20	0.30	0.25			
All D	imens	ions ir	n mm			

a) Actual shape depending upon manufacturing technology used.

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-QFN2020-12 (Type B)

Dimensions	Value
Dimensions	(in mm)
С	0.450
Х	0.450
X1	1.000
X2	0.750
X3	2.300
Y	0.300
Y1	1.000
Y2	1.650
Y3	2.300

Mechanical Data

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu Finish, Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.007 grams (Approximate)



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